

The Future of Analog IC Technology

DESCRIPTION

The MPQ2143H is a monolithic, step-down, switch-mode converter with internal power MOSFETs. It can achieve up to 3A continuous output current from a 2.5V to 5.5V input voltage with excellent load and line regulation. The output voltage can be regulated as low as 0.6V.

Constant-on-time control provides fast transient response and eases loop stabilization. Faultcondition protections include cycle-by-cycle current limiting and thermal shutdown.

The MPQ2143H is available in small QFN-10 package and requires only a minimal number of readily-available standard external components.

The MPQ2143H is ideal for a wide range of applications including high-performance DSPs, FPGAs, and portable instruments.

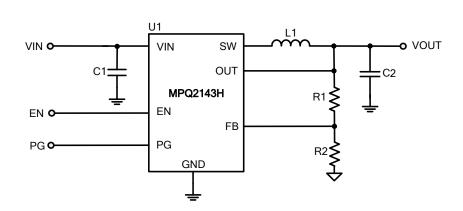
FEATURES

- Wide 2.5V to 5.5V Operating Input Range
- Output Voltage as Low as 0.6V
- 100% Duty Cycle in Dropout
- Up to 3A Output Current
- $80m\Omega$ and $40m\Omega$ Internal Power MOSFET Switches
- Default 2.0MHz Switching Frequency
- EN and Power-Good for Power Sequencing
- Cycle-by-Cycle Over-Current Protection
- Auto Discharge at Power Off
- Short-Circuit Protect with Hiccup Mode
- Stable with Low-ESR Output Ceramic Capacitors
- Available in QFN-10 (2mmx3mm) Package

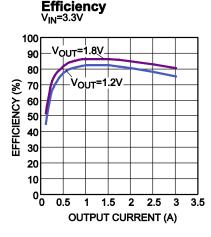
APPLICATIONS

- Low Voltage I/O System Power
- Handheld/Battery-powered Systems
- Wireless/Networking Cards

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TYPICAL APPLICATION





ORDERING INFORMATION

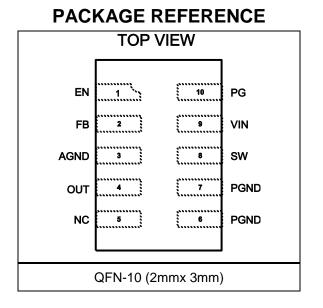
Part Number*	Package	Top Marking
MPQ2143HGD	QFN-10(2mmx3mm)	See Below

* For Tape & Reel, add suffix –Z (e.g. MPQ2143HGD–Z).

TOP MARKING

AMT
YWW
LLL

AMT: product code of MPQ2143HGD; Y: year code; WW: week code: LLL: lot number;





ABSOLUTE MAXIMUM RATINGS (1)

Supply Voltage V _{IN} 6V
V _{SW}
-0.3V (-5V for <10ns) to V _{IN} +0.3V (8V for <10ns)
All Other Pins0.3V to +6 V
Junction Temperature 150°C
Lead Temperature
Continuous Power Dissipation $(T_A = 25^{\circ}C)$ ⁽²⁾
1.9W
Storage Temperature65°C to +150°C
(0)

Recommended Operating Conditions ⁽³⁾

Supply Voltage V _{IN}	2.5V to 5.5V
Output Voltage Vout	0.6V to V _{IN} -0.5V
Operating Junction Temp.	(T _J)40°C to +150°C

Thermal Resistance⁽⁴⁾ θ_{JA} θ_{JC}

QFN-10 (2mmx3mm) 65 13 ... °C/W

Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T_J (MAX), the junction-toambient thermal resistance θ_{JA} , and the ambient temperature T_A. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P_D (MAX) = (T_J (MAX)-T_A)/ θ_{JA} . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the device will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.

ELECTRICAL CHARACTERISTICS

 $V_{IN} = 5V$, $T_J = -40^{\circ}C$ to 125°C, Typical value is tested at $T_J=+25^{\circ}C$. The limit over temperature is guaranteed by characterization, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Max	Units
	M	$T_J = 25^{\circ}C$	591	91 600 609	609	m)/
Feedback Voltage	Vfb	$T_J = -40^{\circ}C$ to $125^{\circ}C$	588	600	612	mV
Feedback Current	I _{FB}	$T_J = 25^{\circ}C, V_{FB} = 0.63V$		10		nA
PFET Switch ON Resistance	Rdson_p			80		mΩ
NFET Switch ON Resistance	R _{DSON_N}			40		mΩ
Switch Leakage		$\label{eq:VEN} \begin{array}{l} V_{\text{EN}} = 0V, \ V_{\text{IN}} = 5V, \\ V_{\text{SW}} = 0V \ \text{and} \ 5V, \\ T_{\text{J}} = 25^{\circ}\text{C} \end{array}$		0.1	2	μA
PFET Current Limit		$T_J = 25^{\circ}C$	3.9	4.5	6	А
ON Time	tou	VIN=5V, VOUT=1.5V		150		
ON TIME	ton	VIN=3.6V, VOUT=1.5V		200		ns
	fs	V _{IN} =3.3V, V _{OUT} =1.5V, T _J =25°C	1800	2000		
Switching Frequency	fs	V _{IN} =3.3V, V _{OUT} =1.5V, T _J =-40°C to 125°C	1700		3000	kHz
Minimum OFF Time	t _{MIN-OFF}			30		ns
Soft-Start Time	t _{SS-ON}	V _{IN} =3.6V, V _{OUT} =1.5V, 10% to 90%		1.3		ms
Soft-Stop Time	tss-off	V_{IN} =3.6V, V_{OUT} =1.5V, 90% to 10%		1		ms
Power-Good Upper Trip Threshold	PGн	FB falling when PG turn to high voltage		110		%
Power-Good Upper Trip Hysteresis	PG _{H_Hys}			5		%
Power-Good Lower Trip Threshold	PG∟	FB Rising when PG turn to high voltage		90		%
Power-Good Lower Trip Hysteresis	$PG_{L_{Hys}}$			5		%
Power-Good Delay	PGD			110		μs
Power-Good Sink Current Capability	V_{PG-L}	Sink 1mA			400	mV
Power-Good Logic High Voltage	V_{PG-H}	$V_{IN}=5V, V_{FB}=0.6V$	4.85			V
Power-Good Internal Pull-Up Resistor	R_{PG}			500		kΩ
Under-Voltage Lockout Threshold Rising			2.0	2.2	2.4	V
Under-Voltage Lockout Threshold Hysteresis				150		mV



ELECTRICAL CHARACTERISTICS

 $V_{IN} = 5V$, $T_J = -40^{\circ}C$ to 125°C, Typical value is tested at $T_J=+25^{\circ}C$. The limit over temperature is guaranteed by characterization, unless otherwise noted.

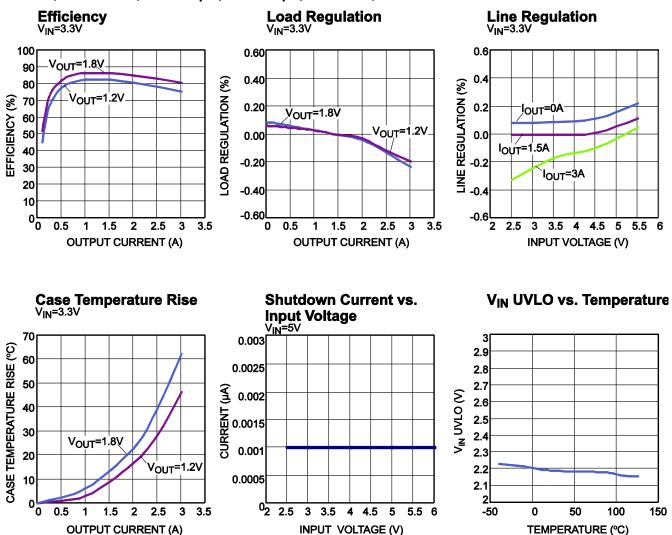
Parameter	Symbol	Condition	Min	Тур	Max	Units
EN Input Logic Low Voltage					0.4	V
EN Input Logic High Voltage			1.2			V
EN Input Current		V _{EN} =2V		2		μA
		V _{EN} =0V		0.1		μA
Supply Current (Shutdown)		V _{EN} =0V		0.1		μA
Thermal Shutdown (5)				170		°C
Thermal Hysteresis (5)				30		°C

Notes:

5) Design Guarantee, no production test.

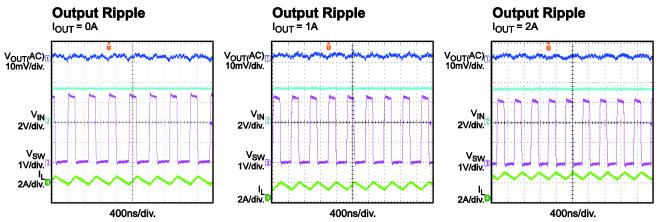
TYPICAL PERFORMANCE CHARACTERISTICS

 $V_{IN} = 5V$, $V_{OUT} = 1.2V$, $L = 0.47\mu$ H, $C_{OUT}=22\mu$ F, $T_A = 25^{\circ}$ C, unless otherwise noted.

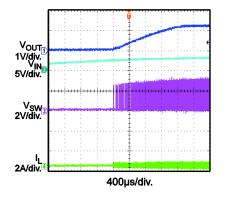


TYPICAL PERFORMANCE CHARACTERISTICS (continued)

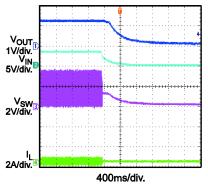
 $V_{IN} = 3.3V$, $V_{OUT} = 1.2V$, $L = 0.47\mu$ H, $C_{OUT}=22\mu$ F, $T_A = 25^{\circ}$ C, unless otherwise noted.



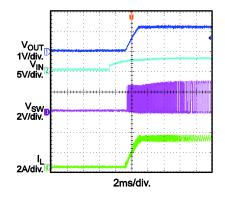
VIN Start Up without Load



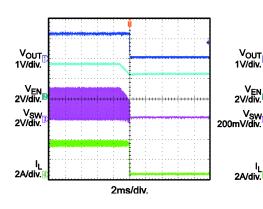
VIN Shutdown without Load



VIN Start Up with 3A Load

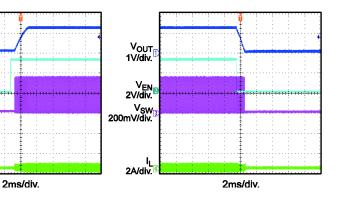


VIN Shutdown with 3A Load



EN Start Up without Load

EN Shutdown without Load



VOUT

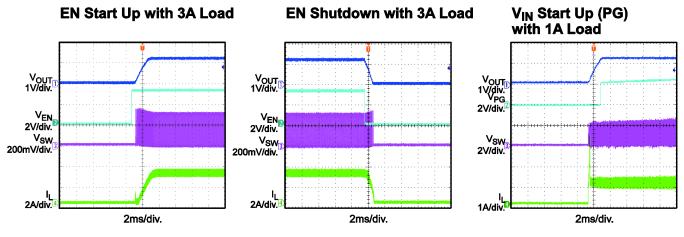
1V/div.

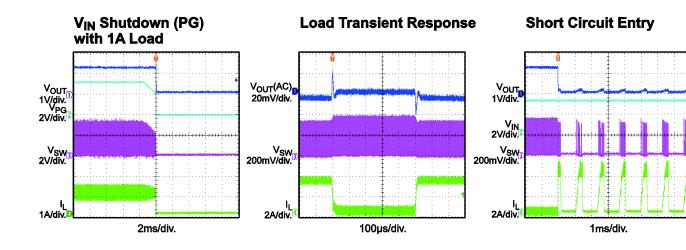
V_{EN} 2V/div.

2A/div.

TYPICAL PERFORMANCE CHARACTERISTICS (continued)

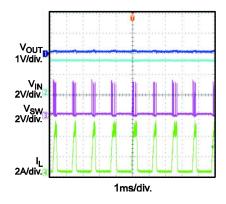
 $V_{IN} = 3.3V$, $V_{OUT} = 1.2V$, $L = 0.47\mu$ H, $C_{OUT}=22\mu$ F, $T_A = 25^{\circ}$ C, unless otherwise noted.



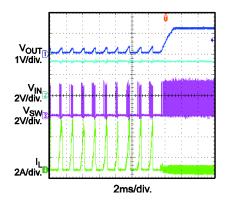


Short Circuit

mps'



Short Circuit Recovery





PIN FUNCTIONS

QFN-10 Pin #	Name	Description	
1	EN	On/Off Control	
2	FB	Feedback pin. Connect an external resistor divider from the output to GND to set th output voltage.	
3	AGND	Analog ground. Reference for the internal control circuit.	
4	OUT	Input Sense. For output voltage feedback.	
5	NC	Not Connected. It can be floated or connected to PGND for thermal.	
6, 7	PGND	Power Ground	
8	SW	Switch Output	
9	VIN	/IN Supply Voltage. The MPQ2143H operates from a 2.5V-to-5.5V unregulated input. C prevents large voltage spikes from appearing at the input.	
10	Power-Good Indicator. The pin output is an open drain that connects to VIN by an intern PG pull-up resistor. PG is pulled up to VIN when the FB voltage is within 10% of the regulation level. If FB voltage is out of that regulation range, it is LOW.		



FUNCTIONAL BLOCK DIAGRAM

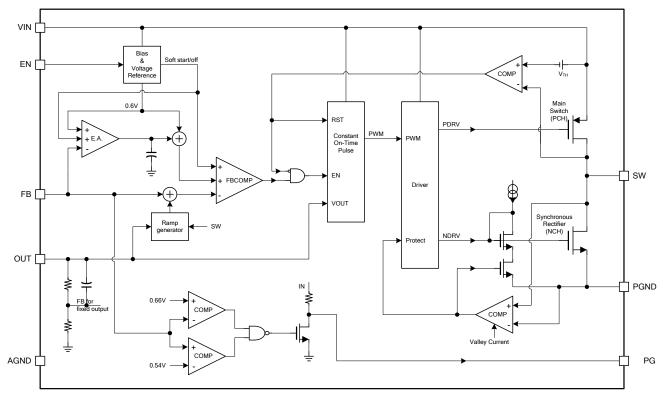


Figure 1: Functional Block Diagram



OPERATION

The MPQ2143H uses constant-on-time control with input-voltage feed-forward to stabilize the switching frequency over its full input range. It can achieve up to 3A continuous output current from a 2.5V to 5.5V input voltage with excellent load and line regulation. The output voltage can be regulated as low as 0.6V.

Constant-On-Time Control

When compared to fixed-frequency PWM control, constant on-time control offers a simpler control loop and faster transient response. By using input-voltage feed-forward, the MPQ2143H maintains a nearly constant switching frequency across the entire input and output voltage range. The switching pulse ON time can be estimated as:

 $T_{on}=V_{OUT}/V_{IN}\times 0.500 \mu s$

To prevent inductor current runaway during the load transient, the MPQ2143H has a fixed minimum OFF time of 50ns. However, this minimum OFF time limit does not affect the operation of the MPQ2143H in steady state in any way.

Enable

When the input voltage exceeds the undervoltage lockout (UVLO) threshold—typically 2.2V—the MPQ2143H is enabled by pulling the EN pin above 1.2V. Leaving the EN pin floating or grounded will disable the MPQ2143H. There is an internal $1M\Omega$ resistor from the EN pin to ground.

Soft-Start/Stop

MPQ2143H has a built-in soft-start that ramps up the output voltage at a constant slew rate that avoids overshooting at startup. The softstart time is typically about 1.3ms. When disabled, the MPQ2143H ramps down the internal reference voltage to allow the load to linearly discharge the output.

Power Good Indicator

MPQ2143H has an open drain with $500k\Omega$ pullup resistor pin for power good (PG) indication. When the FB pin is within $\pm 10\%$ of regulation voltage (0.6V), the PG pin is pulled up to VIN by the internal resistor. If the FB pin voltage is outside the $\pm 10\%$ window, the PG pin is pulled to ground by an internal MOSFET. The MOSFET has a maximum R_{dson} of less than 100Ω .

Current Limit

The MPQ2143H has a 4.5A current limit for the high side switch (HS-FET). When the HS-FET hits its current limit, the MPQ2143H enters hiccup mode until the current drops to prevent the inductor current from building and possibly damaging the components.

Short Circuit and Recovery

The MPQ2143H also enters short-circuit protection (SCP) mode when it hits the current limit, and tries to recover from the short circuit by entering hiccup mode. In SCP, the MPQ2143H disables the output power stage, discharges a soft-start capacitor, and then enacts a soft-start procedure. If the short-circuit condition still holds after soft-start ends, the MPQ2143H repeats this operation until the short circuit ceases and output rises back to regulation level.

APPLICATION INFORMATION COMPONENT SELECTION

Setting the Output Voltage

The external resistor divider sets the output voltage (see the Typical Application schematic on page 1). The feedback resistor R1 must account for both stability and dynamic response, and thus can not be too large or too small. Choose an R1 value between $120k\Omega$ and $200k\Omega$. R2 is then given by:

$$R2 = \frac{R1}{\frac{V_{out}}{0.6} - 1}$$

The feedback circuit is shown as Figure 2.

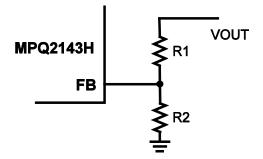


Figure 2: Feedback Network

Table 1 lists the recommended resistors values for common output voltages.

 Table 1: Resistor Values for Common Output

 Voltages

V _{OUT} (V)	R1 (kΩ)	R2 (kΩ)
1.0	200(1%)	300(1%)
1.2	200(1%)	200(1%)
1.5	200(1%)	133(1%)
2.5	200(1%)	63.2(1%)
3.3	200(1%)	44.2(1%)

Selecting the Inductor

A 0.47 μ H to 1.5 μ H inductor is recommended for most applications. For highest efficiency, chose an inductor with a DC resistance less than 15m Ω . For most designs, the inductance value can be derived from the following equation.

$$L_{1} = \frac{V_{OUT} \times (V_{IN} - V_{OUT})}{V_{IN} \times \Delta I_{L} \times f_{OSC}}$$

Where ΔI_{L} is the inductor ripple current.

Choose an inductor current to be approximately 30% of the maximum load current. The maximum inductor peak current is:

$$\mathbf{I}_{\text{L(MAX)}} = \mathbf{I}_{\text{LOAD}} + \frac{\Delta \mathbf{I}_{\text{L}}}{2}$$

Selecting the Input Capacitor

The input current to the step-down converter is discontinuous, and requires a capacitor to supply the AC current to the step-down converter while maintaining the DC input voltage. Use low-ESR capacitors for the best performance. Ceramic capacitors with X5R or X7R dielectrics are highly recommended because of their low ESR values and small temperature coefficients. For most applications, a 10μ F capacitor is sufficient. For higher output voltage, use 47μ F to improve system stability.

Since the input capacitor absorbs the input switching current it requires an adequate ripple current rating. The RMS current in the input capacitor can be estimated by:

$$\mathbf{I_{C1}} = \mathbf{I_{LOAD}} \times \sqrt{\frac{V_{OUT}}{V_{IN}}} \times \left(1 - \frac{V_{OUT}}{V_{IN}}\right)$$

The worse case condition occurs at V_{IN} = $2V_{\text{OUT}},$ where:

$$I_{C1} = \frac{I_{LOAD}}{2}$$

For simplification, choose an input capacitor whose RMS current rating greater than half of the maximum load current.

The input capacitor can be electrolytic, tantalum or ceramic. When using electrolytic or tantalum capacitors, use a small high-quality ceramic capacitor (0.1μ F), placed as close to the IC as possible. When using ceramic capacitors, make sure that they have enough capacitance to prevent excessive voltage ripple at input. The input voltage ripple caused by capacitance can be estimated by:

$$\Delta V_{\text{IN}} = \frac{I_{\text{LOAD}}}{f_{\text{S}} \times C1} \times \frac{V_{\text{OUT}}}{V_{\text{IN}}} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right)$$



Selecting the Output Capacitor

The output capacitor (C2) maintains the output DC voltage. Use ceramic capacitors. Low-ESR capacitors keep the output voltage ripple low. The output voltage ripple can be estimated by:

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{f_{\text{S}} \times L_{1}} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right) \times \left(R_{\text{ESR}} + \frac{1}{8 \times f_{\text{S}} \times C2}\right)$$

Where L_1 is the inductor value and R_{ESR} is the equivalent series resistance of the output capacitor.

Using ceramic capacitors, the impedance at the switching frequency is dominated by the capacitance. The output voltage ripple is mainly caused by the capacitance. For simplification, the output voltage ripple can be estimated by:

$$\Delta V_{\text{OUT}} = \frac{V_{\text{OUT}}}{8 \times {f_{\text{S}}}^2 \times L_1 \times C2} \times \left(1 - \frac{V_{\text{OUT}}}{V_{\text{IN}}}\right)$$

For tantalum or electrolytic capacitors, the ESR dominates the impedance at the switching frequency. For simplification, the output ripple can be approximated as:

$$\Delta V_{\text{out}} = \frac{V_{\text{out}}}{f_{\text{s}} \times L_{1}} \times \left(1 - \frac{V_{\text{out}}}{V_{\text{IN}}}\right) \times R_{\text{esr}}$$

The characteristics of the output capacitor also affect the stability of the regulation system.

PCB Recommendation of MPQ2143H

Proper layout of the switching power supplies is very important, and sometimes critical for proper operation. For high-frequency switching converters, poor layout could lead to poor line or load regulation and stability issues.

The high current paths (GND, IN, and SW) should be placed very close to the device using short, direct, and wide traces. The input capacitor needs to be as close as possible to the IN and GND pins. The external feedback resistors should be placed next to the FB pin. Keep the switching node SW short and away from the feedback network.

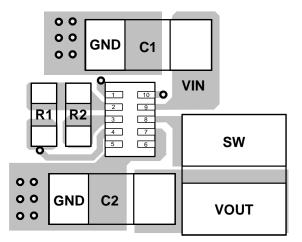


Figure 3: Layout Recommendation



TYPICAL APPLICATION CIRCUITS

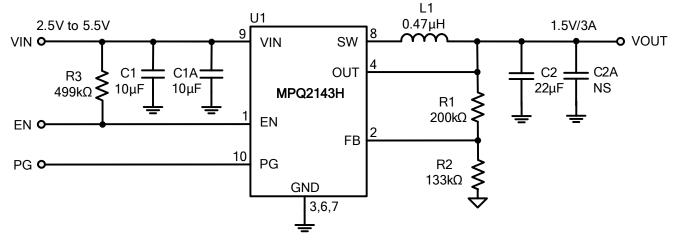
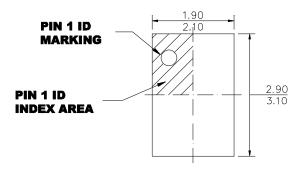


Figure 4: MPQ2143H Typical Application Circuit



PACKAGE INFORMATION

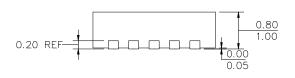
QFN-10 (2mmx3mm)



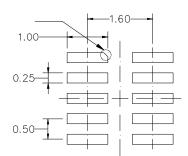
0.65 0.75 10 0.20 0.30 0.50 BSC 6 5 PIN 1 ID

TOP VIEW





SIDE VIEW



RECOMMENDED LAND PATTERN

NOTE:

 ALL DIMENSIONS ARE IN MILLIMETERS.
 EXPOSED PADDLE SIZE DOES NOT INCLUDE MOLD FLASH.
 LEAD COPLANARITY SHALL BE 0.10 MILLIMETERS MAX.
 JEDEC REFERENCE IS MO-220.
 DRAWING IS NOT TO SCALE.

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